

## Ultra Low Jitter Oscillator

### Features

- Frequency range
- 1MHz~200Mhz @3.3V
- 1MHz~125MHz @1.8V
- Supply voltage 1.65V ~ 3.63V
- Output Clock Tri-State Mode
- CMOS output clock
- Operating temperature -40~125°C
- RoHS compliant & Pb free
- AEC-Q100 compliant (option)
- SMD seam sealing ceramic package
- 2.0mm x1.6mm, 2.5mm x2.0mm, 3.2mm x2.5mm

### Applications

- SATA, SAS, Ethernet, PCI Express, video, wireless.
- Computing, storage, networking, telecom, Industrial control.

**Table1. Electrical Characteristics**

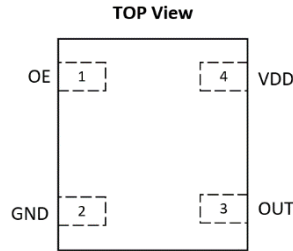
Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Output Frequency Range	F	1	-	200	MHz	V <sub>DD</sub> =3.3V
		1	-	125		V <sub>DD</sub> =1.8V
Frequency Stability	F <sub>stab</sub>	-20	-	+20	PPM	-40~85
		-30	-	+30		-40~105
		-100	-	+100		-40~125
Operating Temperature Range	T <sub>use</sub>	-40	-	+125	°C	
Supply Voltage	V <sub>DD</sub>	1.65	1.8	1.95	V	
		2.97	3.3	3.63		
Current Consumption	I <sub>DD</sub>	-	-	3.4	mA	15pF Load, f=27MHz, V <sub>DD</sub> =3.3V
		-	-	22		15pF Load, f=40MHz, V <sub>DD</sub> =3.3V
OE mode disable current	I <sub>od</sub>	-	-	10	uA	When OE=GND, output is Pulled Down
PDB mode standby Current	I <sub>std</sub>	-	-	10	uA	When OE=GND, output is Pulled Down
Duty Cycle	DC	45		55	%	
Rise/Fall Time	Tr, Tf	-	1.5	-	nS	15pF load, 10%~90% V <sub>DD</sub> , high drive (V <sub>DD</sub> =3.3V)
Output Voltage High	V <sub>OH</sub>	V <sub>DD</sub> -0.4	-	-	V <sub>DD</sub>	I <sub>OH</sub> =-4mA, I <sub>OL</sub> =4mA, Standard Drive
Output Voltage Low	V <sub>OL</sub>	-	-	0.4	V <sub>DD</sub>	
Input Voltage High	V <sub>IH</sub>	70%	-	-	V <sub>DD</sub>	Pin1, OE
Input Voltage Low	V <sub>IL</sub>	-	-	30%	V <sub>DD</sub>	Pin1, OE
Startup Time	T <sub>start</sub>	-	5	7	mS	Measure from the time V <sub>DD</sub> reaches its rated minimum value.
OE Enable/Disable Time	T <sub>oe</sub>	-	-	10	nS	OE function; Ta=25 °C, 15pFload. Add one clock period to this measurement for a usable clock output.
Resume Time	T <sub>resume</sub>	-	-	7	mS	In PDB mode, Ta=25 °C, 15pFload
PK-PK Period Jitter	T <sub>jitt</sub>	-	200	300	pS	F=27MHz, V <sub>DD</sub> = 3.3V
		-	220	400	pS	F=27MHz, V <sub>DD</sub> =1.8V
RMS Phase Jitter	T <sub>phj</sub>	-	-	0.7	pS	F=27MHz, integration bandwidth=12kHz to 5MHz, V <sub>DD</sub> =1.8V
First year Aging	F <sub>aging</sub>	-1.5	-	+1.5	PPM	25 °C
10-year Aging		-5	-	+5	PPM	

Notes:

1: All electrical specifications in the above table are specified with 15pF output load and for all V<sub>DD</sub> unless otherwise stated.

**Table2. Pin Configuration**

Pin	Symbol	Functionality	
1	OE	Output Enable	H or Open, Specified frequency output L: output is high impedance. Only output driver is disabled.
		PDB mode	H or Open, Specified frequency output L: output is low. Device goes to sleep mode. Supply current reduces to I <sub>std</sub> .
2	GND	Power	Electrical ground
3	OUT	Output	Oscillator output
4	VDD	Power	Power supply voltage



**Table3. Absolute Maximum**

Attempted operation outside the absolute maximum ratings of the part may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

Parameter	Min.	Max.	Unit
Storage Temperature	-60	150	°C
VDD	-0.5	7	V
Electrostatic Discharge	-	2000	V
Soldering Temperature		260	°C
Junction Temperature		150	°C

**Phase Noise Plot**

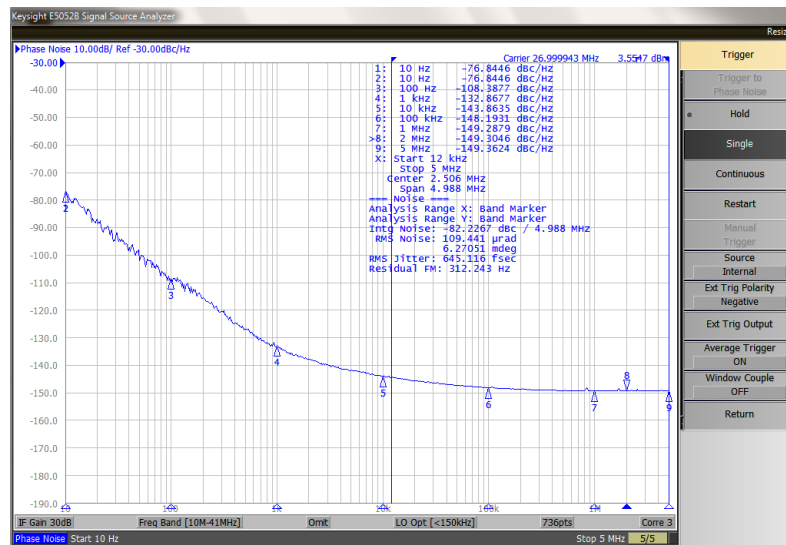


Figure 1. Phase Noise, 27MHz, 1.8V, LVCOMS Output

**Test Circuit and Waveform**

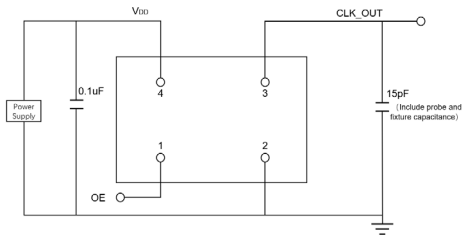


Figure 2. Test Circuit

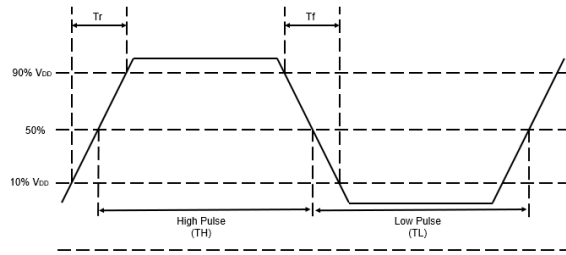
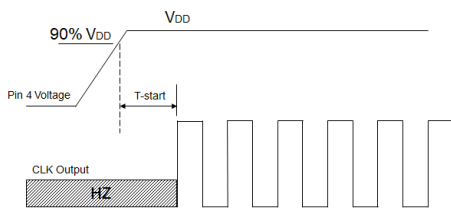


Figure 3. Waveform

Notes:

2. Duty Cycle is computed as Duty Cycle = TH/Period.

**Timing Diagram**



T-start: Time to start from power-off

Figure 4. Startup Timing (OE mode)

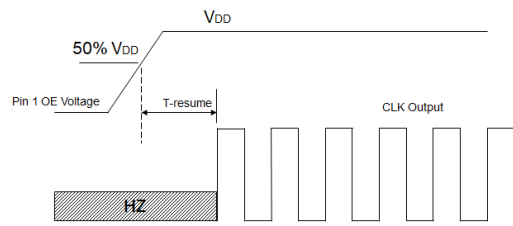
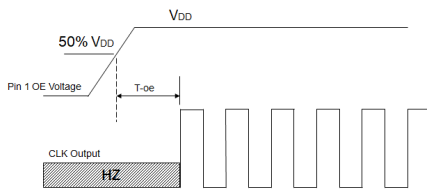
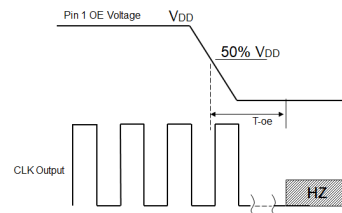


Figure 5. Standby Resume Timing (PDB mode)



T-oe: Time to re-enable the clock output

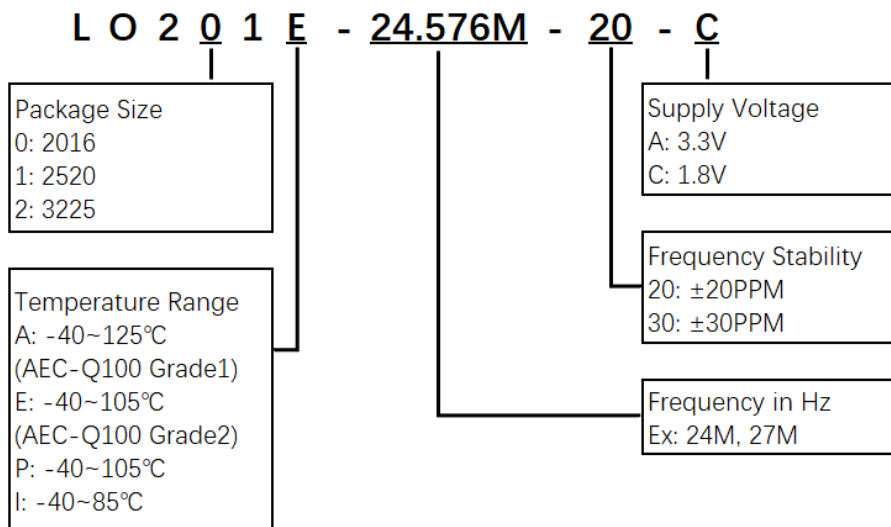
Figure 6. OE Enable Timing



T-oe: Time to re-enable the clock output

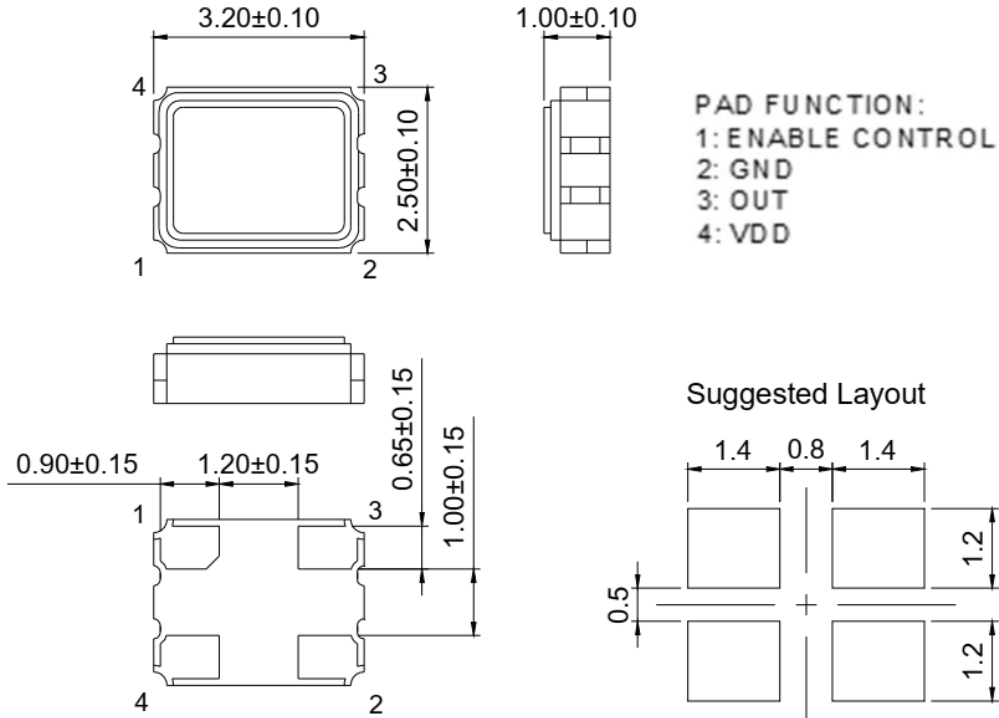
Figure 7. OE Disable Timing

**Ordering Information**

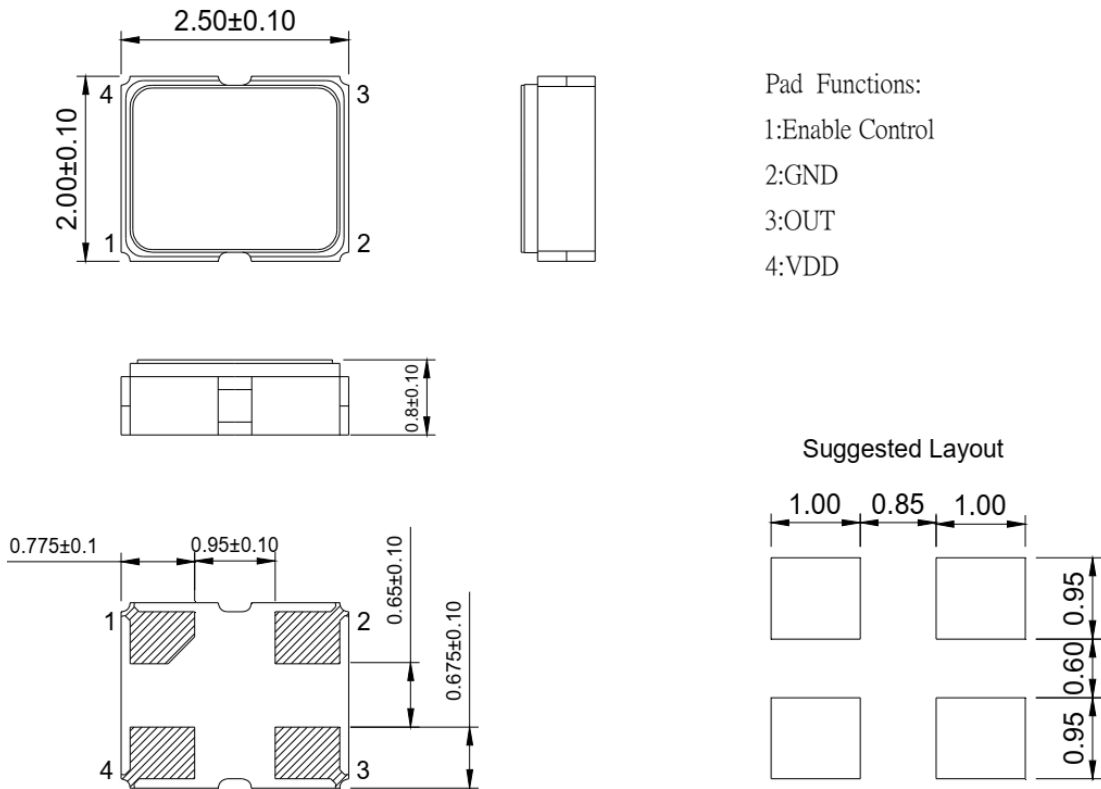


**Dimensions**

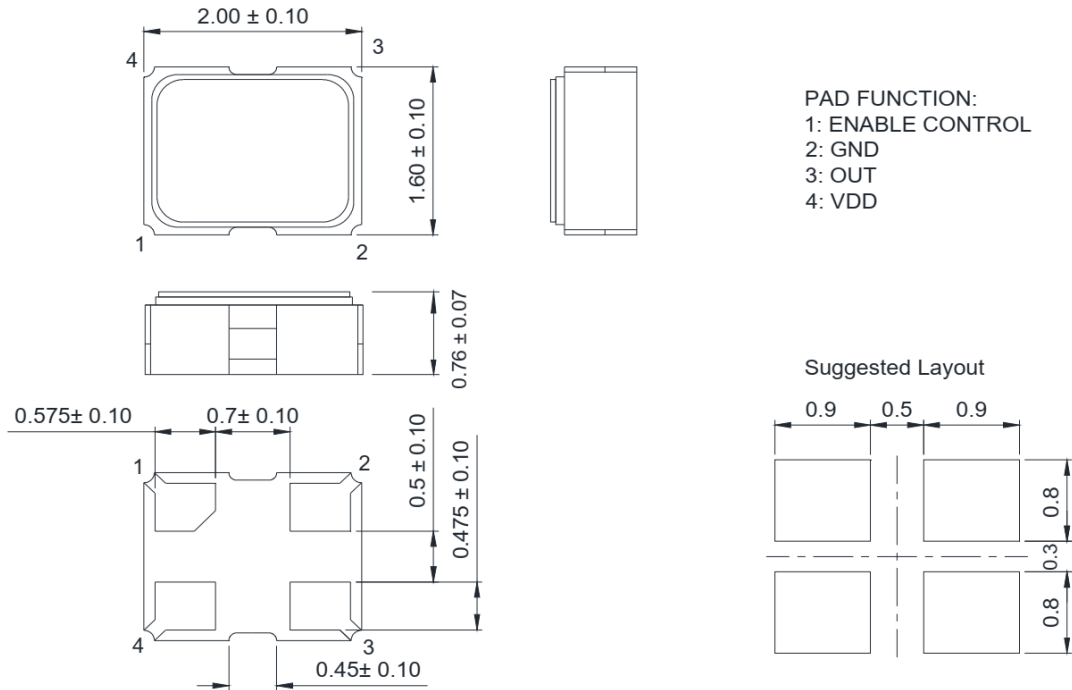
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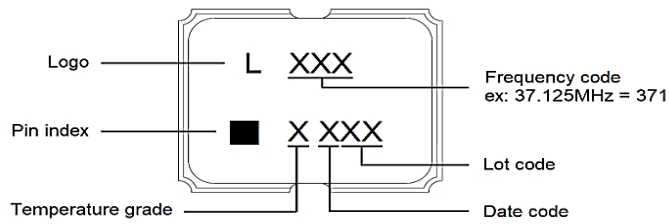
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**2016**



**Marking**



Temperature Grade	Temperature Range	Frequency Stability (PPM)
A	-40~125°C(AEC-Q100 Grade1)	±100
E	-40~105°C (AEC-Q100 Grade2)	±30
P	-40~105°C	±30
I	-40~85°C	±20

## Revision History

Revision Number	Date of Release	Changes
1.0	03/29/2021	1) Preliminary datasheet
1.1	04/29/2021	1) Ordering information 2) Marking
1.2	05/21/2021	1) Add dimensions
1.3	09/09/2021	1) Add temperature range -40~125°C
1.4	10/26/2021	1) Add I temperature Grade
1.5	12/06/2021	1) Update the AEC-Q100 Grade 1
1.6	11/15/2022	1) Modify the PPM in the marking information 2) Updated the electrical characteristics. 3) Updated the phase noise plot.